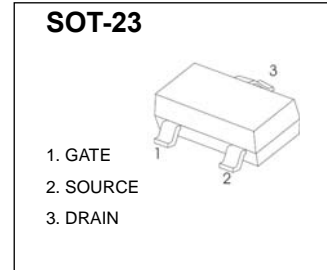




**SOT-23 Plastic-Encapsulate MOSFETS**

**CJ3420** N-Channel Enhancement Mode Field Effect Transistor

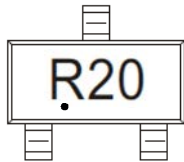
$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D$
20 V	24mΩ@ 10V	6A
	27mΩ@4.5V	
	42mΩ@2.5V	
	74mΩ@1.8V	



**DESCRIPTION**

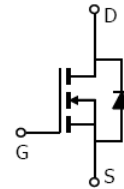
The CJ3420 uses advanced trench technology to provide excellent  $R_{DS(on)}$ . This device is suitable for use as a uni-directional or bi-directional load switch.

**MARKING**



R20 = Device code  
Solid dot = Green molding compound device.

**Equivalent Circuit**



**Maximum ratings ( $T_a=25^\circ\text{C}$  unless otherwise noted)**

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	±12	
Continuous Drain Current	$I_D$	6	A
Pulsed Drain Current	$I_{DM}$	25	
Power Dissipation	$P_D$	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^\circ\text{C}/\text{W}$
Operation Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 ~+150	$^\circ\text{C}$

# MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25\text{ }^\circ\text{C}$  unless otherwise specified

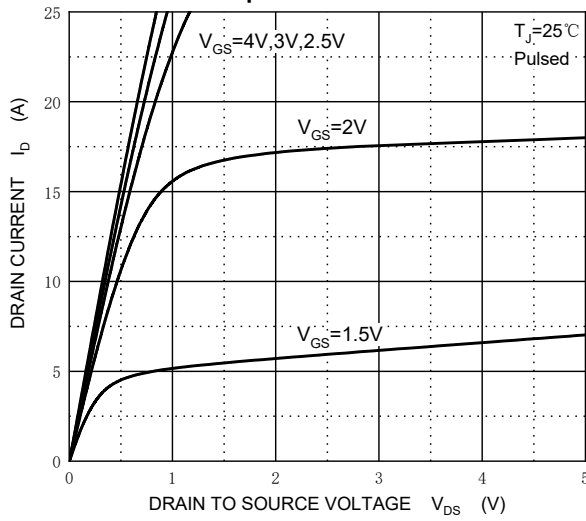
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = 16V, V_{GS} = 0V, T_J = 25\text{ }^\circ\text{C}$			1	$\mu A$
		$V_{DS} = 16V, V_{GS} = 0V, T_J = 125\text{ }^\circ\text{C}$			1	mA
Gate-source leakage current	$I_{GSS}$	$V_{GS} = \pm 12V, V_{DS} = 0V$			$\pm 100$	nA
<b>On characteristics</b>						
Drain-source on-resistance <sup>②</sup>	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 6A$		19	24	m $\Omega$
		$V_{GS} = 4.5V, I_D = 5A$		22	27	m $\Omega$
		$V_{GS} = 2.5V, I_D = 4A$		27	42	m $\Omega$
		$V_{GS} = 1.8V, I_D = 2A$		38	74	m $\Omega$
Forward transconductance	$g_{FS}$	$V_{DS} = 5V, I_D = 3.8A$	4			S
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.5	0.7	1.0	V
<b>Dynamic Characteristics<sup>③</sup></b>						
Input capacitance	$C_{iss}$	$V_{DS} = 10V, V_{GS} = 0V, f = 1MHz$		630		pF
Output capacitance	$C_{oss}$			164		pF
Reverse transfer capacitance	$C_{rss}$			137		pF
Gate resistance	$R_g$	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		1.5		$\Omega$
<b>Switching Characteristics<sup>③</sup></b>						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = 10V, V_{DS} = 15V,$ $R_L = 2.7\Omega, R_{GEN} = 3\Omega$		5.5		ns
Turn-on rise time	$t_r$			14		ns
Turn-off delay time	$t_{d(off)}$			29		ns
Turn-off fall time	$t_f$			10.2		ns
Total Gate Charge	$Q_g$	$V_{DS} = 10V, I_D = 6A,$ $V_{GS} = 4.5V$		8.8		nC
Gate-Source Charge	$Q_{gs}$			1		nC
Gate-Drain Charge	$Q_{gd}$			3.7		nC
<b>Drain-source diode characteristics and maximum ratings</b>						
Diode forward voltage <sup>②</sup>	$V_{SD}$	$I_S = 1A, V_{GS} = 0V$		0.75	1	V
Continuous drain-source diode forward current	$I_S$				6	A
Pulsed drain-source diode forward current <sup>①</sup>	$I_{SM}$				25	A

Notes:

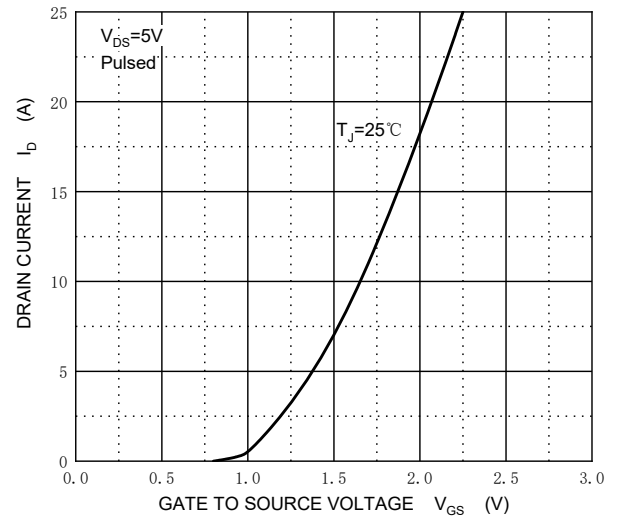
- 1.Repetitive Rating : Pulse width limited by maximum junction temperature.
- 2.Pulse Test : Pulse Width $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
- 3.Guaranteed by design, not subject to production testing.

# Typical Characteristics

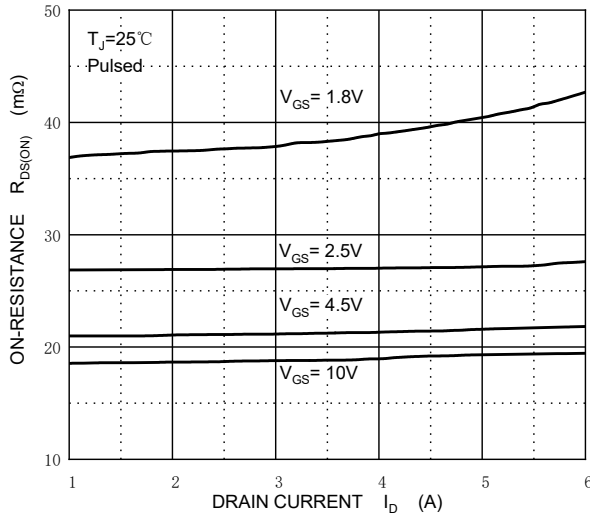
**Output Characteristics**



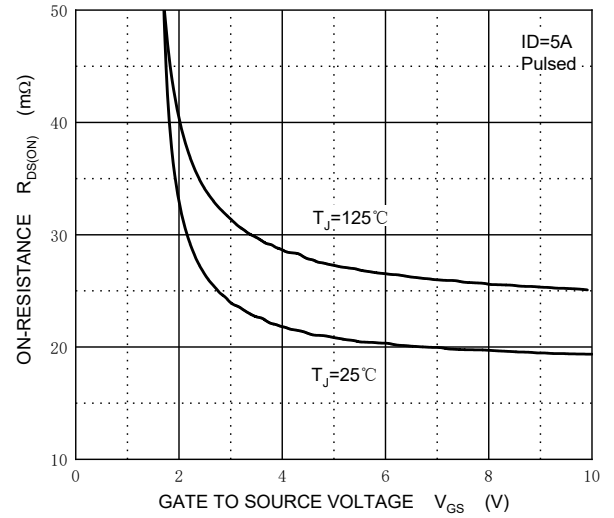
**Transfer Characteristics**



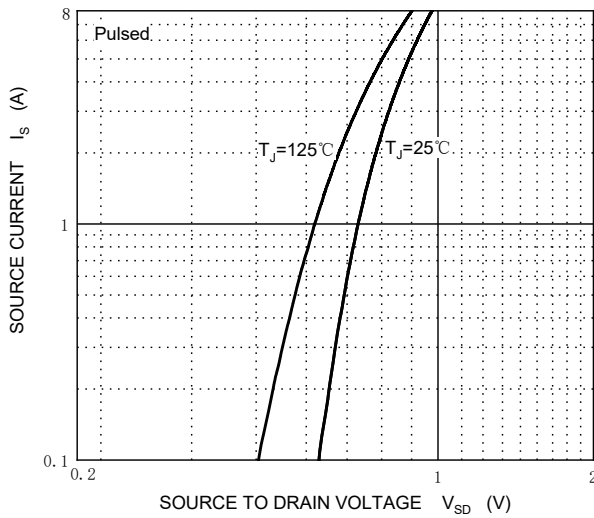
**$R_{DS(ON)}$  —  $I_D$**



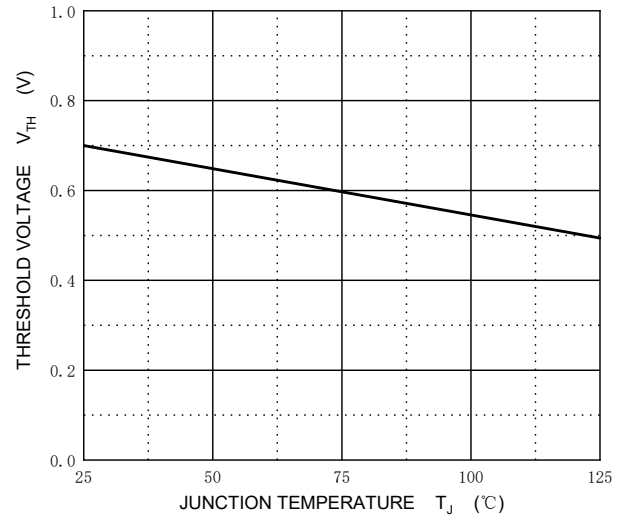
**$R_{DS(ON)}$  —  $V_{GS}$**



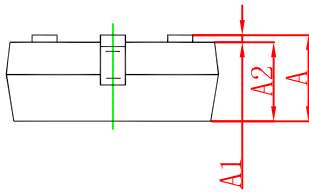
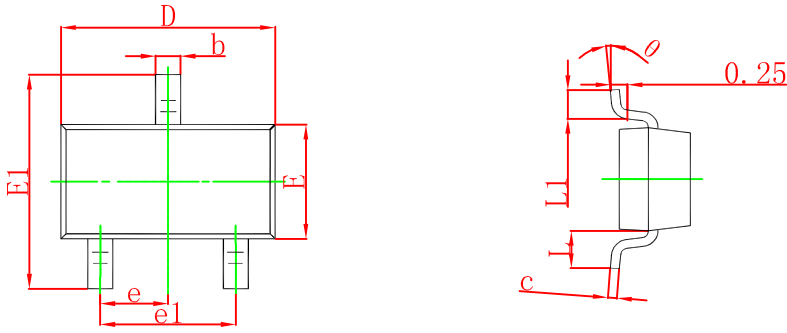
**$I_S$  —  $V_{SD}$**



**Threshold Voltage**

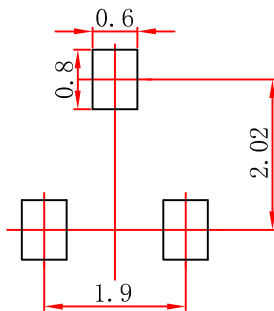


## SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

## SOT-23 Suggested Pad Layout



**Note:**

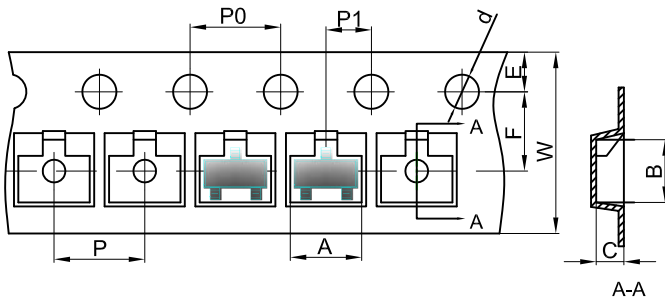
1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

**NOTICE**

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

# SOT-23 Tape and Reel

## SOT-23 Embossed Carrier Tape



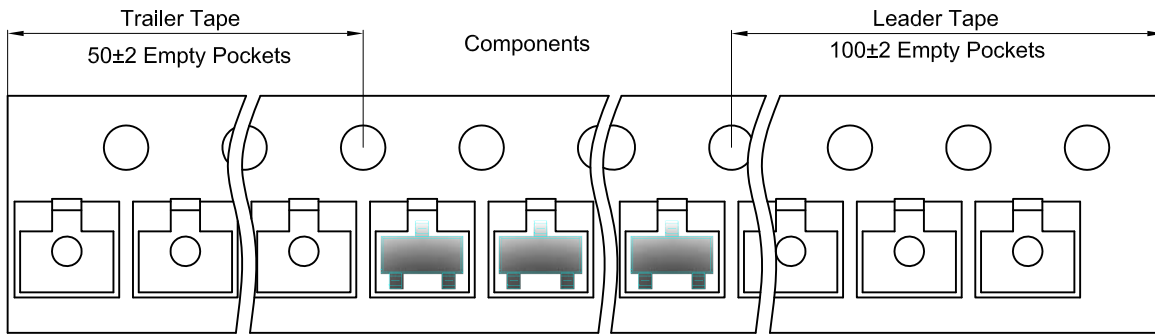
### Packaging Description:

SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

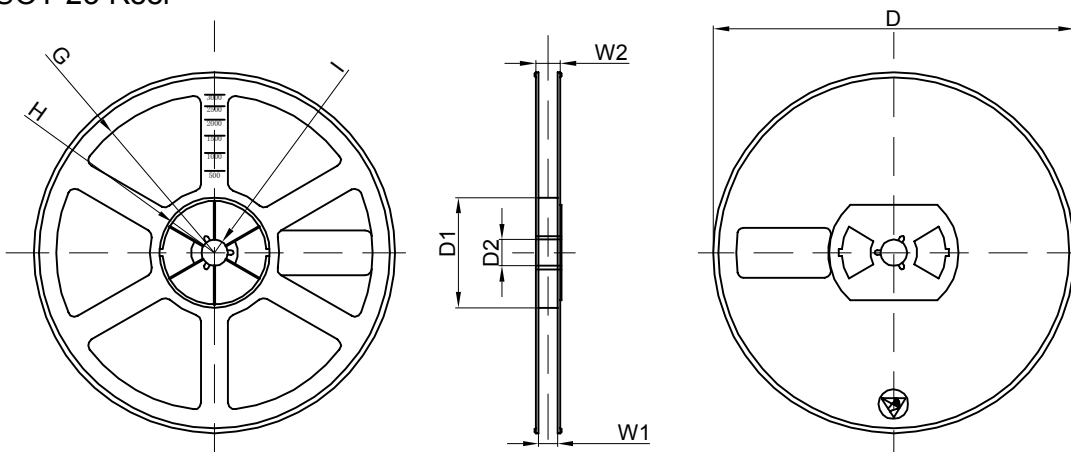
Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

## SOT-23 Tape Leader and Trailer



## SOT-23 Reel



Dimensions are in millimeter

Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	